

FEATURES

High Speed:

50 MHz Unity Gain Bandwidth

350 V/ μ s Slew Rate

70 ns Settling Time to 0.01%

Low Power:

7.5 mA Max Power Supply Current Per Amp

Easy to Use:

Drives Unlimited Capacitive Loads

50 mA Min Output Current Per Amplifier

Specified for +5 V, ± 5 V and ± 15 V Operation

2.0 V p-p Output Swing into a 150 Ω Load

($V_S = +5$ V)

Good Video Performance

Differential Gain & Phase Error of 0.07% & 0.11°

Excellent DC Performance:

2.0 mV Max Input Offset Voltage

APPLICATIONS

Unity Gain ADC/DAC Buffer

Cable Drivers

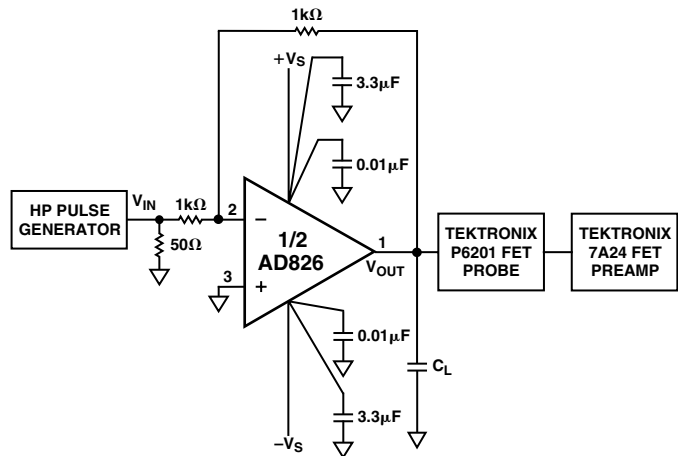
8- and 10-Bit Data Acquisition Systems

Video Line Driver

Active Filters

PRODUCT DESCRIPTION

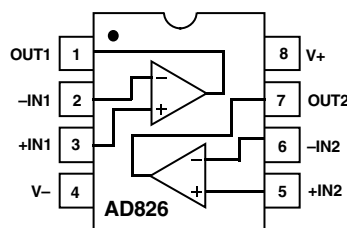
The AD826 is a dual, high speed voltage feedback op amp. It is ideal for use in applications which require unity gain stability and high output drive capability, such as buffering and cable driving. The 50 MHz bandwidth and 350 V/ μ s slew rate make the AD826 useful in many high speed applications including: video, CATV, copiers, LCDs, image scanners and fax machines.



Driving a Large Capacitive Load

CONNECTION DIAGRAM

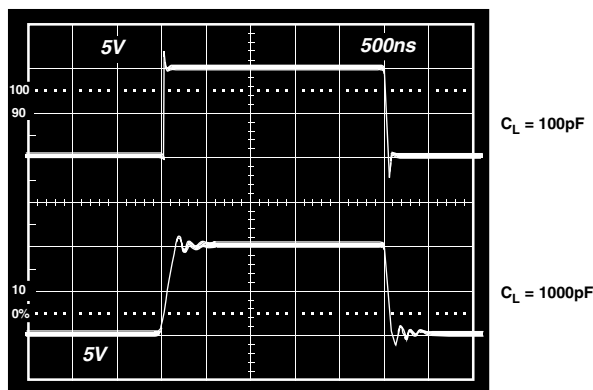
8-Lead Plastic Mini-DIP and SO Package



The AD826 features high output current drive capability of 50 mA min per amp, and is able to drive unlimited capacitive loads. With a low power supply current of 15 mA max for both amplifiers, the AD826 is a true general purpose operational amplifier.

The AD826 is ideal for power sensitive applications such as video cameras and portable instrumentation. The AD826 can operate from a single +5 V supply, while still achieving 25 MHz of bandwidth. Furthermore the AD826 is fully specified from a single +5 V to ± 15 V power supplies.

The AD826 excels as an ADC/DAC buffer or active filter in data acquisition systems and achieves a settling time of 70 ns to 0.01%, with a low input offset voltage of 2 mV max. The AD826 is available in small 8-lead plastic mini-DIP and SO packages.



AD826—SPECIFICATIONS (@ T_A = +25°C, unless otherwise noted)

Parameter	Conditions	V _S	Min	Typ	Max	Unit
DYNAMIC PERFORMANCE						
Unity Gain Bandwidth		±5 V	30	35		MHz
		±15 V	45	50		MHz
Bandwidth for 0.1 dB Flatness	Gain = +1	0, +5 V	25	29		MHz
		±5 V	10	20		MHz
		±15 V	25	55		MHz
		0, +5 V	10	20		MHz
Full Power Bandwidth ¹	V _{OUT} = 5 V p-p R _{LOAD} = 500 Ω	±5 V		15.9		MHz
	V _{OUT} = 20 V p-p R _{LOAD} = 1 kΩ	±15 V		5.6		MHz
Slew Rate	R _{LOAD} = 1 kΩ	±5 V	200	250		V/μs
	Gain = -1	±15 V	300	350		V/μs
		0, +5 V	150	200		V/μs
Settling Time to 0.1%	-2.5 V to +2.5 V	±5 V		45		ns
	0 V-10 V Step, A _V = -1	±15 V		45		ns
	-2.5 V to +2.5 V	±5 V		70		ns
	0 V-10 V Step, A _V = -1	±15 V		70		ns
NOISE/HARMONIC PERFORMANCE						
Total Harmonic Distortion	F _C = 1 MHz	±15 V		-78		dB
Input Voltage Noise	f = 10 kHz	±5 V, ±15 V		15		nV/√Hz
Input Current Noise	f = 10 kHz	±5 V, ±15 V		1.5		pA/√Hz
Differential Gain Error (R _I = 150 Ω)	NTSC	±15 V		0.07	0.1	%
	Gain = +2	±5 V		0.12	0.15	%
		0, +5 V		0.15		%
Differential Phase Error (R _I = 150 Ω)	NTSC	±15 V		0.11	0.15	Degrees
	Gain = +2	±5 V		0.12	0.15	Degrees
		0, +5 V		0.15		Degrees
DC PERFORMANCE						
Input Offset Voltage	T _{MIN} to T _{MAX}	±5 V to ±15 V		0.5	2	mV
					3	mV
Offset Drift				10		μV/°C
Input Bias Current	T _{MIN} T _{MAX}	±5 V, ±15 V		3.3	6.6	μA
					10	μA
Input Offset Current	T _{MIN} T _{MAX}	±5 V, ±15 V			4.4	μA
				25	300	nA
Offset Current Drift	T _{MIN} to T _{MAX}				500	nA
Open-Loop Gain				0.3		nA/°C
	V _{OUT} = ±2.5 V	±5 V				
	R _{LOAD} = 500 Ω		2	4		V/mV
	T _{MIN} to T _{MAX}		1.5			V/mV
	R _{LOAD} = 150 Ω		1.5	3		V/mV
	V _{OUT} = ±10 V	±15 V				
	R _{LOAD} = 1 kΩ		3.5	6		V/mV
	T _{MIN} to T _{MAX}		2	5		V/mV
	V _{OUT} = ±7.5 V	±15 V				
	R _{LOAD} = 150 Ω (50 mA Output)		2	4		V/mV
INPUT CHARACTERISTICS						
Input Resistance				300		kΩ
Input Capacitance				1.5		pF
Input Common-Mode Voltage Range		±5 V	+3.8	+4.3		V
			-2.7	-3.4		V
		±15 V	+13	+14.3		V
			-12	-13.4		V
		0, +5 V	+3.8	+4.3		V
			+1.2	+0.9		V
Common-Mode Rejection Ratio	V _{CM} = ±2.5 V, T _{MIN} -T _{MAX}	±5 V	80	100		dB
	V _{CM} = ±12 V	±15 V	86	120		dB
	T _{MIN} to T _{MAX}	±15 V	80	100		dB

Parameter	Conditions	V _s	Min	Typ	Max	Unit
OUTPUT CHARACTERISTICS						
Output Voltage Swing	R _{LOAD} = 500 Ω	±5 V	3.3	3.8		±V
	R _{LOAD} = 150 Ω	±5 V	3.2	3.6		±V
	R _{LOAD} = 1 kΩ	±15 V	13.3	13.7		±V
	R _{LOAD} = 500 Ω	±15 V	12.8	13.4		±V
	R _{LOAD} = 500 Ω	0, +5 V	+1.5, +3.5			V
Output Current		±15 V	50			mA
		±5 V	50			mA
		0, +5 V	30			mA
Short-Circuit Current		±15 V		90		mA
Output Resistance	Open Loop			8		Ω
MATCHING CHARACTERISTICS						
Dynamic						
Crosstalk	f = 5 MHz	±15 V		-80		dB
Gain Flatness Match	G = +1, f = 40 MHz	±15 V		0.2		dB
Slew Rate Match	G = -1	±15 V		10		V/μs
DC						
Input Offset Voltage Match	T _{MIN} -T _{MAX}	±5 V to ±15 V		0.5	2	mV
Input Bias Current Match	T _{MIN} -T _{MAX}	±5 V to ±15 V		0.06	0.8	μA
Open-Loop Gain Match	V _O = ±10 V, R _{LOAD} = 1 kΩ, T _{MIN} -T _{MAX}	±15 V	0.15	0.01		mV/V
Common-Mode Rejection Ratio Match	V _{CM} = ±12 V, T _{MIN} -T _{MAX}	±15 V	80	100		dB
Power Supply Rejection Ratio Match	±5 V to ±15 V, T _{MIN} -T _{MAX}		80	100		dB
POWER SUPPLY						
Operating Range	Dual Supply		±2.5		±18	V
	Single Supply		+5		+36	V
Quiescent Current/Amplifier		±5 V		6.6	7.5	mA
		±5 V			7.5	mA
		±15 V			7.5	mA
		±15 V		6.8	7.5	mA
Power Supply Rejection Ratio	T _{MIN} to T _{MAX} V _S = ±5 V to ±15 V, T _{MIN} to T _{MAX}		75	86		dB

NOTES

¹Full power bandwidth = slew rate/2 π V_{PEAK}.

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS¹

Supply Voltage ±18 V

Internal Power Dissipation²

Plastic (N) See Derating Curves

Small Outline (R) See Derating Curves

Input Voltage (Common Mode) ±V_S

Differential Input Voltage ±6 V

Output Short Circuit Duration See Derating Curves

Storage Temperature Range (N, R) -65°C to +125°C

Operating Temperature Range -40°C to +85°C

Lead Temperature Range (Soldering 10 seconds) ... +300°C

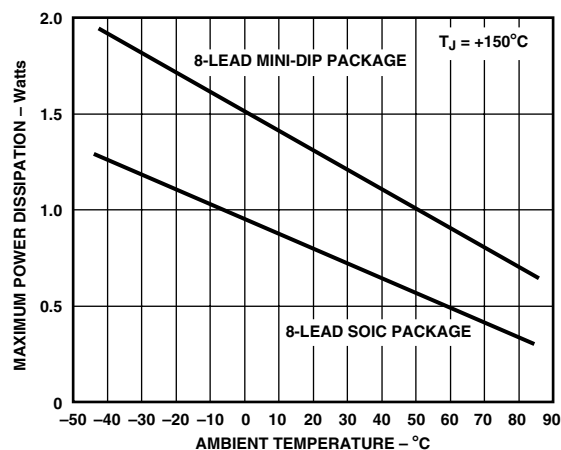
NOTES

¹Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.²Specification is for device in free air: 8-lead plastic package, θ_{JA} = 100°C/watt; 8-lead SOIC package, θ_{JA} = 155°C/watt.**ORDERING GUIDE**

Model	Temperature Range	Package Description	Package Option
AD826AN	-40°C to +85°C	8-Lead Plastic DIP	N-8
AD826AR	-40°C to +85°C	8-Lead Plastic SOIC	SO-8
AD826AR-REEL7	-40°C to +85°C	7" Tape & Reel SOIC	SO-8
AD826AR-REEL	-40°C to +85°C	13" Tape & Reel SOIC	SO-8

ESD SUSCEPTIBILITY

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 volts, which readily accumulate on the human body and on test equipment, can discharge without detection. Although the AD826 features proprietary ESD protection circuitry, permanent damage may still occur on these devices if they are subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid any performance degradation or loss of functionality.

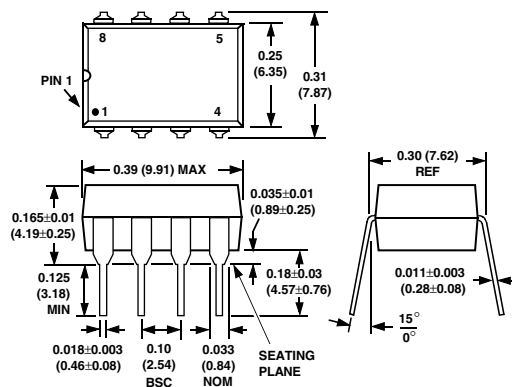


Maximum Power Dissipation vs. Temperature for Different Package Types

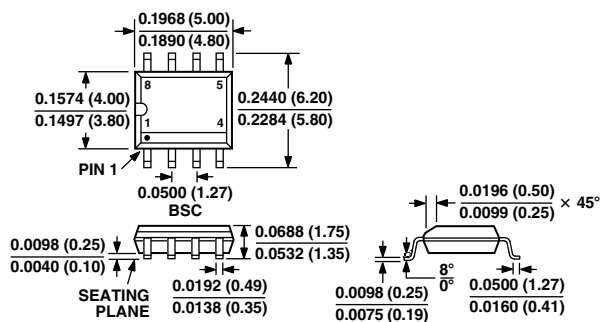
OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

8-Lead Plastic Mini-DIP (N) Package



8-Lead SO (R) Package



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